

Power transistor (60V, 2A)

2SC5880

●Features

- 1) High speed switching.
(Tf : Typ. : 35ns at Ic = 2A)
- 2) Low saturation voltage, typically
(Typ. : 200mV at Ic = 1.0A, Ib = 100mA)
- 3) Strong discharge power for inductive load and capacitance load.
- 4) Complements the 2SA2093

●Applications

Low frequency amplifier
High speed switching

●Structure

NPN Silicon epitaxial planar transistor

●Packaging specifications

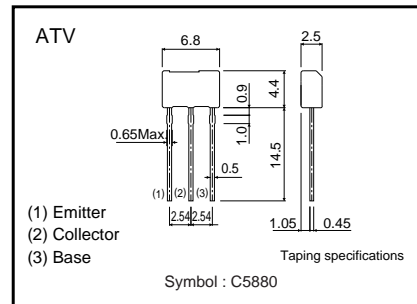
Type	Package	Taping
	Code	TV2
	Basic ordering unit (pieces)	2500
2SC5880		○

●Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit
Collector-base voltage		V _{CB0}	60	V
Collector-emitter voltage		V _{CE0}	60	V
Emitter-base voltage		V _{EB0}	6	V
Collector current	DC	I _c	2	A
	Pulsed	I _{cP}	4	A *
Power dissipation		P _c	1.0	W
Junction temperature		T _j	150	°C
Range of storage temperature		T _{stg}	-55 to 150	°C

*Pw=10ms

●External dimensions (Unit : mm)



Transistors

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Collector-emitter breakdown voltage	BV _{CEO}	60	–	–	V	I _C =1mA
Collector-base breakdown voltage	BV _{CBO}	60	–	–	V	I _C =100μA
Emitter-base breakdown voltage	BV _{EBO}	6	–	–	V	I _E =100μA
Collector cut-off current	I _{CBO}	–	–	1.0	μA	V _{CB} =40V
Emitter cut-off current	I _{EBO}	–	–	1.0	μA	V _{EB} =4V
Collector-emitter saturation voltage	V _{CE(sat)}	–	200	500	mV	I _C =1.0A I _B =0.1A
DC current gain	h _{FE}	120	–	390	–	V _{CE} =2V I _C =100mA
Transition frequency	f _r	–	200	–	MHz	V _{CE} =10V I _E = –100mA f=10MHz
Corrector output capacitance	C _{ob}	–	10	–	pF	V _{CB} =10V I _E =0mA f=1MHz
Turn-on time	T _{on}	–	50	–	ns	I _C =2A I _{B1} =200mA
Storage time	T _{stg}	–	120	–	ns	I _{B2} = –200mA
Fall time	T _f	–	35	–	ns	V _{CC} ≒ 25V

*Non repetitive pulse

●h_{FE} RANK

Q	R
120–270	180–390

●Electrical characteristic curves

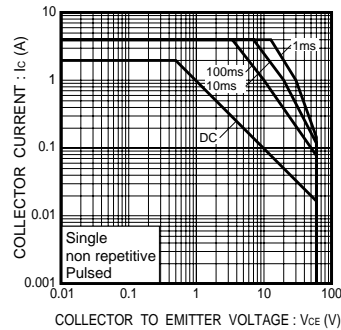


Fig.1 Safe Operating Area

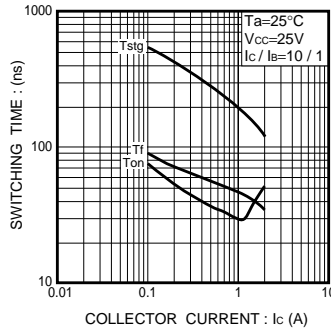


Fig.2 Switching Time

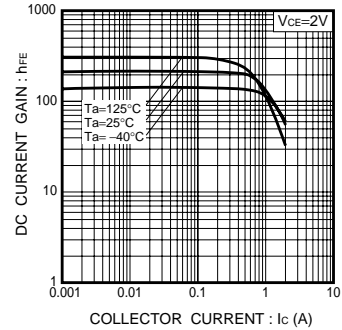


Fig.3 DC Current Gain vs. Collector Current (I)

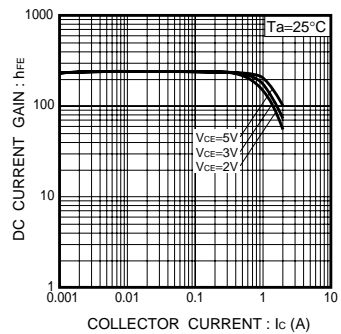


Fig.4 DC Current Gain vs. Collector Current (II)

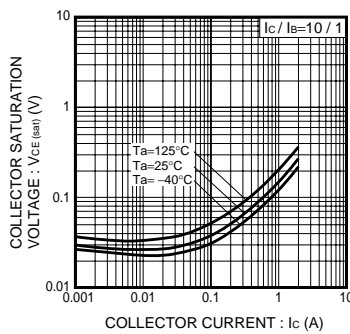


Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current (I)

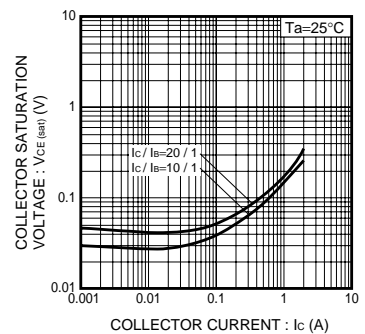


Fig.6 Collector-Emitter Saturation Voltage vs. Collector Current (II)

Transistors

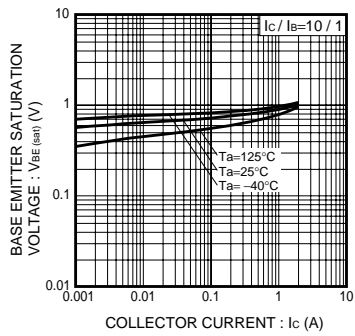


Fig.7 Base-Emitter Saturation Voltage vs. Collector Current

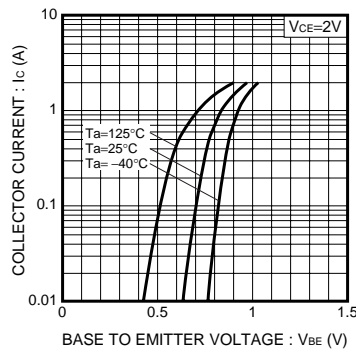


Fig.8 Grounded Emitter Propagation Characteristics

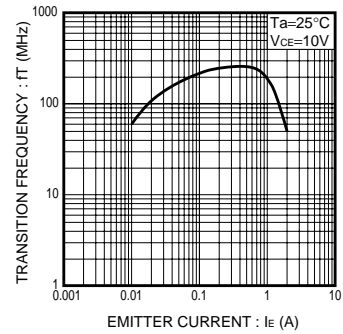


Fig.9 Transition Frequency

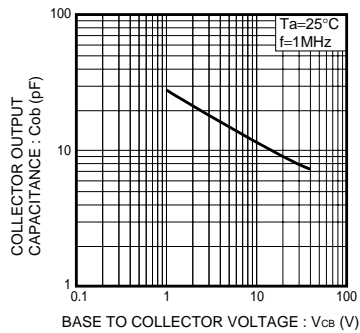
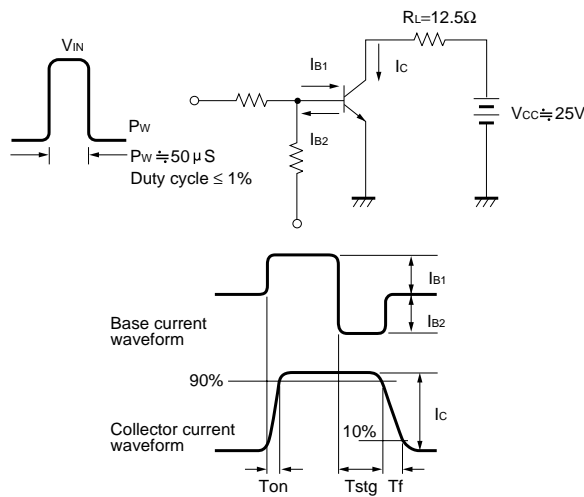


Fig.10 Collector Output Capacitance

●Switching characteristics measurement circuits



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